13th "Trento" Workshop on Advanced Silicon Radiation Detectors



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Recent Results with Ultra-Fast Silicon Detectors

The performance of Ultra-fast Silicon Detectors (UFSD) has been measured pre-rad and after neutron irradiation up to $6e15 \text{ n/cm}^2$.

Of special interest are UFSD with 35 and 50 micron thickness.

The measured time resolution is traced back to the evolution with fluence of internal gain, rise time and noise.

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